

DS89C21 Differential CMOS Line Driver and Receiver Pair

Check for Samples: [DS89C21](#)

FEATURES

- Meets TIA/EIA-422-A (RS-422) and CCITT V.11 Recommendation
- **LOW POWER** Design—15 mW Typical
- **Guaranteed AC Parameters:**
 - Maximum Driver Skew 2.0 ns
 - Maximum Receiver Skew 4.0 ns
- **Extended Temperature Range:** –40°C to +85°C
- Available in SOIC Packaging
- Operates over 20 Mbps
- Receiver OPEN Input Failsafe Feature

DESCRIPTION

The DS89C21 is a differential CMOS line driver and receiver pair, designed to meet the requirements of TIA/EIA-422-A (RS-422) electrical characteristics interface standard. The DS89C21 provides one driver and one receiver in a minimum footprint. The device is offered in an 8-pin SOIC package.

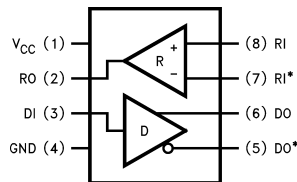
The CMOS design minimizes the supply current to 6 mA, making the device ideal for use in battery powered or power conscious applications.

The driver features a fast transition time specified at 2.2 ns, and a maximum differential skew of 2 ns making the driver ideal for use in high speed applications operating above 10 MHz.

The receiver can detect signals as low as 200 mV, and also incorporates hysteresis for noise rejection. Skew is specified at 4 ns maximum.

The DS89C21 is compatible with TTL and CMOS levels (DI and RO).

Connection Diagram



See Package Number D (R-PDSO-G8)

Truth Table Driver

Input	Outputs	
DI	DO	DO*
H	H	L
L	L	H

Truth Table Receiver

Inputs	Output
RI–RI*	RO
$V_{DIFF} \geq +200 \text{ mV}$	H
$V_{DIFF} \leq -200 \text{ mV}$	L
OPEN ⁽¹⁾	H

(1) Non-terminated



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings ⁽¹⁾⁽²⁾⁽³⁾

Supply Voltage (V_{CC})	7V
Driver Input Voltage (DI)	-1.5V to $V_{CC} + 1.5V$
Driver Output Voltage (DO, \overline{DO})	-0.5V to +7V
Receiver Input Voltage— V_{CM}	
(RI, \overline{RI})	$\pm 14V$
Differential Receiver Input	$\pm 14V$
Voltage— V_{DIFF} (RI, \overline{RI})	
Receiver Output Voltage (RO)	-0.5V to $V_{CC} + 0.5V$
Receiver Output Current (RO)	$\pm 25\text{ mA}$
Storage Temperature Range	
(T_{STG})	-65°C to +150°C
Lead Temperature (T_L)	+260°C
(Soldering 4 sec.)	
Maximum Junction Temperature	150°C
Maximum Package Power Dissipation @+25°C	
D Package	714 mW
Derate D Package	5.7 mW/°C above +25°C

- (1) Absolute Maximum Ratings are those values beyond which the safety of the device cannot be ensured. They are not meant to imply that the devices should be operated at these limits. The tables of [Electrical Characteristics](#) specify conditions for device operation.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) ESD Rating: HBM (1.5 k Ω , 100 pF) all pins $\geq 2000V$. EIAJ (0 Ω , 200 pF) $\geq 250V$

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	4.50	5.50	V
Operating Temperature (T_A)	-40	+85	°C
Input Rise or Fall Time (DI)		500	ns

Electrical Characteristics ⁽¹⁾⁽²⁾

Over recommended supply voltage and operating temperature ranges, unless otherwise specified.

Symbol	Parameter	Conditions		Pin	Min	Typ	Max	Units
DRIVER CHARACTERISTICS								
V _{IH}	Input Voltage HIGH	V _{IN} = V _{CC} , GND, 2.0V, 0.8V		DI	2.0		V _{CC}	V
V _{IL}	Input Voltage LOW				GND		0.8	V
I _{IH} , I _{IL}	Input Current					0.05	±10	µA
V _{CL}	Input Clamp Voltage				I _{IN} = -18 mA		-1.5	V
V _{OD1}	Unloaded Output Voltage	No Load		DO, DO*		4.2	6.0	V
V _{OD2}	Differential Output Voltage	R _L = 100Ω			2.0	3.0		V
ΔV _{OD2}	Change in Magnitude of V _{OD2} for Complementary Output States					5.0	400	mV
V _{OD3}	Differential Output Voltage	R _L = 150Ω			2.1	3.1		V
V _{OD4}	Differential Output Voltage	R _L = 3.9 kΩ				4.0	6.0	V
V _{OC}	Common Mode Voltage	R _L = 100Ω				2.0	3.0	V
ΔV _{OC}	Change in Magnitude of V _{OC} for Complementary Output States					2.0	400	mV
I _{OSD}	Output Short Circuit Current	V _{OUT} = 0V			-30	-115	-150	mA
I _{OFF}	Output Leakage Current	V _{CC} = 0V	V _{OUT} = +6V			0.03	+100	µA
			V _{OUT} = -0.25V		-0.08	-100	µA	
RECEIVER CHARACTERISTICS								
V _{TL} , V _{TH}	Differential Thresholds	V _{IN} = +7V, 0V, -7V		RI, RI*	-200	±25	+200	mV
V _{HYS}	Hysteresis	V _{CM} = 0V			20	50		mV
R _{IN}	Input Impedance	V _{IN} = -7V, +7V, Other = 0V			5.0	9.5		kΩ
I _{IN}	Input Current	Other Input = 0V, V _{CC} = 5.5V and V _{CC} = 0V	V _{IN} = +10V			+1.0	+1.5	mA
			V _{IN} = +3.0V		0	+0.22		mA
			V _{IN} = +0.5V			-0.04		mA
			V _{IN} = -3V		0	-0.41		mA
			V _{IN} = -10V			-1.25	-2.5	mA
V _{OH}	Output HIGH Voltage	I _{OH} = -6 mA	V _{DIFF} = +1V	RO	3.8	4.9		V
			V _{DIFF} = OPEN		3.8	4.9		V
V _{OL}	Output LOW Voltage	I _{OL} = +6 mA, V _{DIFF} = -1V				0.08	0.3	V
I _{OSR}	Output Short Circuit Current	V _{OUT} = 0V			-25	-85	-150	mA
DRIVER AND RECEIVER CHARACTERISTICS								
I _{CC}	Supply Current	No Load	DI = V _{CC} or GND	V _{CC}		3.0	6	mA
			DI = 2.4V or 0.5V			3.8	12	mA

- (1) Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise specified.
- (2) All typicals are given for $V_{CC} = 5.0\text{V}$ and $T_A = 25^\circ\text{C}$.

Switching Characteristics ⁽¹⁾⁽²⁾

Over recommended supply voltage and operating temperature ranges, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Units
DIFFERENTIAL DRIVER CHARACTERISTICS							
t _{PLHD}	Propagation Delay LOW to HIGH	R _L = 100Ω C _L = 50 pF	(Figure 2 Figure 3)	2	4.9	10	ns
t _{PHLD}	Propagation Delay HIGH to LOW			2	4.5	10	ns
t _{SKD}	Skew, t _{PLHD} –t _{PHLD}				0.4	2.0	ns
t _{TLH}	Transition Time LOW to HIGH		(Figure 2 Figure 4)		2.2	9	ns
t _{THL}	Transition Time HIGH to LOW				2.1	9	ns
RECEIVER CHARACTERISTICS							
t _{PLH}	Propagation Delay LOW to HIGH	C _L = 50 pF V _{DIFF} = 2.5V V _{CM} = 0V	(Figure 5 Figure 6)	6	18	30	ns
t _{PHL}	Propagation Delay HIGH to LOW			6	17.5	30	ns
t _{SK}	Skew, t _{PLH} –t _{PHL}				0.5	4.0	ns
t _r	Rise Time		(Figure 7)		2.5	9	ns
t _f	Fall Time				2.1	9	ns

(1) All typicals are given for $V_{CC} = 5.0\text{ V}$ and $T_A = 25^\circ\text{C}$.

(2) $f = 1\text{ MHz}$, t_r and $t_f \leq 6\text{ ns}$.

Parameter Measurement Information

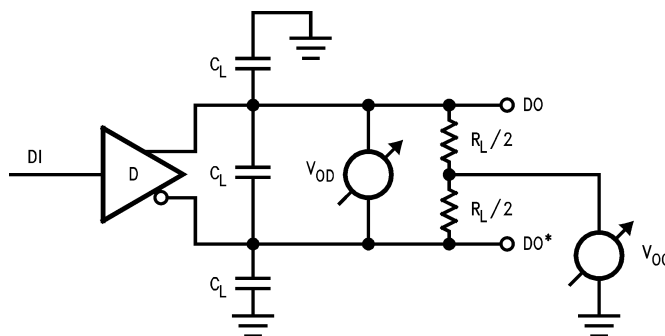
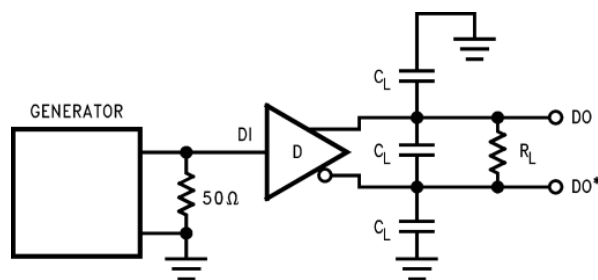


Figure 1. V_{OD} and V_{OC} Test Circuit



$f = 1\text{ MHz}$, t_r and $t_f \leq 6\text{ ns}$.

Figure 2. Driver Propagation Delay Test Circuit

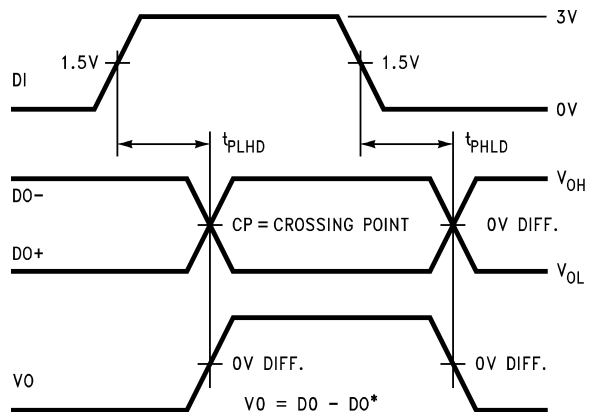


Figure 3. Driver Differential Propagation Delay Timing

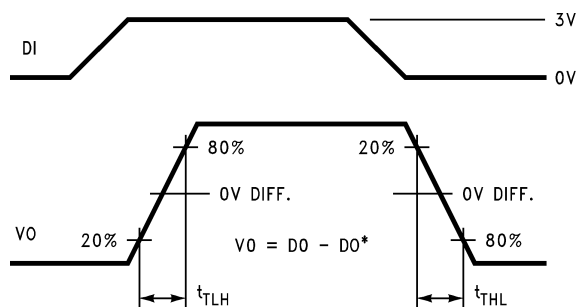
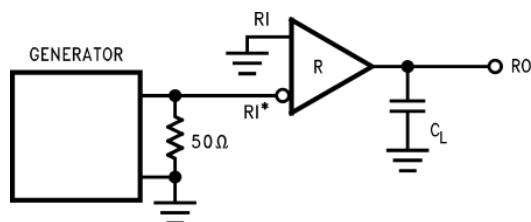


Figure 4. Driver Differential Transition Timing



$f = 1 \text{ MHz}$, t_r and $t_f \leq 6 \text{ ns}$.

Figure 5. Receiver Propagation Delay Test Circuit

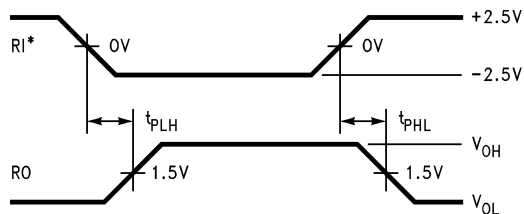


Figure 6. Receiver Propagation Delay Timing

**Figure 7. Receiver Rise and Fall Times**

REVISION HISTORY

Changes from Revision B (April 2013) to Revision C

Page

- Changed layout of National Data Sheet to TI format [6](#)

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
DS89C21TM	NRND	SOIC	D	8	95	TBD	Call TI	Call TI	-40 to 85	DS89C 21TM	
DS89C21TM/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	SN CU SN	Level-1-260C-UNLIM	-40 to 85	DS89C 21TM	Samples
DS89C21TMX	NRND	SOIC	D	8	2500	TBD	Call TI	Call TI	-40 to 85	DS89C 21TM	
DS89C21TMX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	SN CU SN	Level-1-260C-UNLIM	-40 to 85	DS89C 21TM	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS89C21TMX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
DS89C21TMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS89C21TMX	SOIC	D	8	2500	367.0	367.0	35.0
DS89C21TMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AA.

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